

rakon

SMD Temperature Compensated Crystal Oscillator

SMD TCXO using analogue ASIC for compensation and an optional Enable/Disable pin for efficient power management.

Product description

The I(V)T2200J employs an analogue ASIC for the oscillator and a high order temperature compensation circuit in a 2.5 x 2.0 mm size package. The device can be placed in power down mode through a single input pin. During standard operation, power consumption is minimized by operating down to a supply voltage of 1.8V. The I(V)T2200J's high stability, low power consumption, small footprint and powerful compensation method makes it a TCXO ideally suited for demanding GPS mobile applications.

Applications

- Consumer
- Communications
- GPS
- · Feature phone

Features

- Excellent phase noise performance
- Frequency slope and perturbation specifications can be customized to the application requirement
- Standard temperature stability choices are ±0.5ppm, ±1ppm, ±1.5ppm and ±2.5ppm over wide temperature ranges

Specifications

1.0 SPECIFICATION REFERENCES

Line Parameter

1.1

Description IT2200J / IVT2200J / IT2200JP

- Model description RoHS compliant 1.2 Yes
- 1.3 Reference number
- 1.4 Rakon part number

FREQUENCY CHARACTERISTICS 2.0

Line	Parameter	Test Condition	Value	Unit
2.1	Frequency		10 to 52	MHz
2.2	Frequency calibration	Offset from nominal frequency measured at 25°C±2°C	±1 max	ppm
2.3	Reflow shift	Two consecutive reflows as per attached profile after 1 hour recovery at 25°C	±1 max	ppm
2.4	Temperature range	The operating temperature range over which the frequency stability is measured	-40 to 85	°C
2.5	Frequency stability over temperature	Referenced to the midpoint between minimum and maximum frequency value over the specified temperature range. Control voltage set to midpont of control voltage (Note 1)	±0.5 to 2.5	ppm
2.6	Frequency slope	Minimum of 1 frequency reading every 2°C over the operating temperature range (Note 1)	0.1 to 1	ppm/°C
2.7	Static temperature hysteresis	Frequency change after reciprocal temperature ramped over the operating range. Frequency measured before and after at 25°C	0.6 max	ppm
2.8	Sensitivity to supply voltage variations	Supply voltage varied $\pm 5\%$ at $25^{\circ}C$	±0.2 max	ppm
2.9	Sensitivity to load variations	±10% load change at 25°C (Note 2)	±0.2 max	ppm
2.10	Long term stability	Frequency drift over 1 year at 25°C	±1 max	ppm



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Drawing Name: I(V)T2200J Model Outline



LID MARKING *

* Marking information is detailed in the specification.



PIN CONNECTIONS

Pin	IT22J	IVT22J	IT22JP			
1	NC / GND	VCO	Enable / Disable**			
2	GND	GND	GND			
3	OUTPUT	OUTPUT	OUTPUT			
4	Vdd	Vdd	Vdd			
** Connect to VDD or floating to enable TCXO.						

RECOMMENDED PAD LAYOUT - TOP VIEW

	/ To GND			
	External Bypass Cap 100nF 1.39 1.39 2.08 Cap 2.08 Cap 2.08 Cap 2.08 Cap 2.08 Cap 200 No Tracks Including Plains Under Device Cap 200 Log Contractions Capacitor ≥ 1nF			
TITLE: I(V)T2200J MODEL	FILENAME: CAT676 TOLERANCES:			
RELATED DRAWINGS:	REVISION: D XX =			
	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$			
	SCALE: 10:1 X° = ±0.05			
	Millimetres Hole = © 2013 Rakon Limited			

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